



Analysis of the anomalies in graphene thermal properties

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ABSTRACT

A comprehensive analysis of the thermal conductivity of graphene under various conditions is presented in this study. Results obtained from different experimental and theoretical methods are analyzed and discussed for numerous conditions such as preparation process, shape, sample size, wavelength, and temperature. Wide discrepancies in the measured thermal conductivity results were found in many studies in the literature. Based on the cited data for the graphene thermal conductivity, the initially measured thermal conductivities appear to be highly overestimated. Majority of the documented results reported lower values of thermal conductivity than the earlier reported results. Furthermore, large differences in the values of the thermal conductivity of graphene were noticed from the cited results using different experimental and numerical methods (0.14 W/m K–20,000 W/m K). This raised an important question on the accuracy of these methods when measuring thermal conductivity of graphene at nanoscale. We have established the existence of a high degree of anomalies in the value of the thermal conductivity of graphene. Therefore, proper experimental and theoretical studies should be conducted to accurately measure the thermal conductivity of graphene.

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1. Introduction

Graphene, a single layer of carbon atoms bonded in a hexagonal lattice, is considered an excellent conductor of heat and electricity. Among its significant properties, an extremely high thermal conductivity, it has received voluminous attention in scientific and industrial fields over the last decade both experimentally and theoretically [1–12]. This consideration stems from its importance in a variety of important applications such as thermal management and electronic interconnects application [1–4,13–30].

There have been several works discussing the topic of graphene in recent years. For example, Castro Neto et al. [3] considered the basic theoretical aspects of graphene with unusual two-dimensional Dirac-like electronic excitations. Ma et al. [31] focused on recent progress in the synthesis of graphene nanoribbons (GNRs) by different techniques, especially longitudinal unzipping of carbon nanotubes (CNTs). The mechanical, electronic, and magnetic properties and edge reconstruction of GNRs are briefly summarized as well. Choi et al. [32] presented a study on the advancement of research in graphene, in the area of synthesis, properties and applications such as field emission, sensors,

electronics, and energy, the limitations of present knowledge base and future research directions. A study of fundamental electronic properties of two-dimensional graphene with an emphasis on density and temperature-dependent carrier transport in doped or gated graphene structures was provided by Das Sarma [33]. The main feature of that work was a critical comparison between carrier transport in graphene and two-dimensional semiconductor systems (e.g., hetero-structures, quantum wells, inversion layers) so that the unique features of graphene electronic properties arising from its gapless, mass-less, chiral Dirac spectrum were highlighted.

Zhang et al. [34] summarized the recent advances in the study of graphene edges, including edge formation energy, edge reconstruction, method of graphene edge synthesis and the recent progress on metal-passivated graphene edges and the role of edges in graphene CVD growth. The aim of their work was to provide a guideline for readers to gain a clear picture of graphene edges from several aspects, especially the catalyst-passivated graphene edges and their role in graphene CVD growth. Recently, Renteria et al. [35] considered the thermal properties of graphene, few-layer graphene and graphene nanoribbons, and discussed practical applications of graphene in thermal management and energy storage. It was shown that the use of liquid-phase-exfoliated graphene as filler material in phase change materials was promising for thermal management of high-power-density battery packs.

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However, the thermal conductivity measurements of graphene reported to date exhibited contradictory results. For example, Balandin et al. [12] and Ghosh et al. [36] reported that the thermal conductivity of graphene measured by Raman Spectroscopy were 4840–5300 W/m K (2–5 μm diameter) and \sim 3080–5150 W/m K (1–5 μm diameter), respectively. On the other hand, Lee et al. [37] reported that the thermal conductivity of a suspended pristine graphene measured by the same method was ranging from \sim 1800 W/m K near 325 K to \sim 710 W/m K at 500 K. Moreover, Faugeras et al. [11] reported that the thermal conductivity of a suspended graphene disk 44 μm in diameter measured by the same method was 632 W/m K. Although the diameter of the suspended disk used by Faugeras et al. [11] was about nine times the diameter of the graphene used by Balandin et al. [12], the conductivity obtained by Faugeras et al. was about eight times smaller than that obtained by Balandin et al. [12]. Other experimental methods such as microelectrothermal system and scanning thermal microscopy reported values of graphene thermal conductivity in the range of 10–2500 W/m K [38–40,5,41–47]. On the theoretical side, the picture is equally open with estimates varying in an even larger range of thermal conductivity values between 25 and 20,000 W/m K [48,49,40,50–55]. This clearly shows great disagreements in the reported results of graphene thermal conductivity in the literature.

The aim of this investigation is to analyze the discrepancies in the reported thermal conductivity of graphene using different experimental and theoretical techniques. Also, the accuracy of the initially reported thermal conductivity in the literature will be discussed.

2. Experimental methods of measuring thermal conductivity of graphene

Various experimental techniques were used in the literature to measure the thermal conductivity of graphene such as Raman spectroscopy, microelectrothermal system, and scanning thermal microscopy. In what follows, we will elucidate the discrepancies in the measured results of thermal conductivity of graphene.

2.1. Raman spectroscopy

Raman spectroscopy of graphene has received considerable attention since the discovery of graphene [56,57]. Chen et al. [56] measured the thermal conductivity of a graphene monolayer grown by chemical vapor deposition and suspended over holes with different diameters using micro-Raman spectroscopy. The obtained thermal conductivity values of the suspended graphene ranged from (2.6 ± 0.9) to $(3.1 \pm 1.0) \times 10^3$ W/m K near 350 K without showing the sample size dependence predicted for suspended, clean, and flat graphene crystal. Lee et al. [37] measured the thermal conductivity of suspended single-layer graphene as a function of temperature using Raman scattering spectroscopy on clean samples prepared directly on a pre-patterned substrate by mechanical exfoliation without chemical treatments. Thermal conductivity was deduced by analyzing the heat diffusion equation assuming that the substrate is a heat sink at an ambient temperature. The obtained thermal conductivity values range from \sim 1800 W/m K near 325 K to \sim 710 W/m K at 500 K. Cai et al. [6] measured room-temperature thermal conductivity of $(370 + 650/-320)$ W/m K for the supported graphene. The thermal conductivity of the suspended graphene exceeds $(2500 + 1100/-1050)$ W/m K near 350 K and becomes $(1400 + 500/-480)$ W/m K at about 500 K. Jauregui et al. [57] conducted an experimental study to determine the thermal conductivity of graphene using Raman spectroscopy. The thermal conductivity of suspended CVD graphene was in the range of 1500–5000 W/m K using Raman spectroscopy.

Table 1 illustrates measured thermal conductivity values of graphene for various conditions using Raman spectroscopy method. It can be seen from this table that there is large discrepancies in the measured thermal conductivity results. For example, Balandin et al. [12] reported a value of 4840–5300 W/m K for graphene at room temperature, which seems to be substantially higher than those measured by a number of other investigators. On the other hand, Faugeras et al. [11] reported thermal conductivity of 632 W/m K at 660 K for exfoliated graphene which is close to the results reported by Lee et al. [37] at 500 K (\sim 710 W/m K). The most important difference between the analysis of Balandin et al. [12] and the work of Lee et al. [37] and others is the value of the absorptance α of single layer graphene. Balandin et al. [12] used $\alpha = 13\%$, which is several times larger than the value of 2.3% measured and theoretically analyzed by Nair et al. [58]. If one uses $\alpha = 2.3\%$, their thermal conductivity value would reduce to 940 W/m K. Chen et al. [56] measured the thermal conductivity of a graphene monolayer grown by chemical vapor deposition and suspended over holes with different diameters ranging from 2.9 to 9.7 μm measured in vacuum using Raman spectroscopy. The obtained thermal conductivity values of the suspended graphene was ranging from (2.6 ± 0.9) to $(3.1 \pm 1.0) \times 10^3$ W/m K near 350 K.

Table 1 also demonstrates disagreements in the results associated with the effect of sample size on the thermal conductivity of graphene. For example, Ghosh et al. [36] and Balandin et al. [12] showed that as the diameter of the sample increases, the thermal conductivity increases. However, Chen et al. [56] illustrated that the thermal conductivity of graphene does not depend on the size of the sample. The results presented by Lee et al. [37] confirmed this finding. **Fig. 1** demonstrates a wide dispersion of thermal conductivity of single layer graphene across various sample size using Raman Spectroscopy technique at room temperature. The sample size appears not correlating with thermal conductivity results of graphene. Therefore, this area of research would benefit from further studies which adhere to standard set of parameters to produce precise estimate of thermal conductivity of graphene. Lee et al. [37] showed that the thermal conductivity of graphene is strongly temperature dependent. As the temperature increases, the thermal conductivity of graphene decreases using the Raman Spectroscopy method. Using results from different studies in the literature, **Fig. 2** illustrates the effect of varying the temperature on the thermal conductivity of single layer graphene using Raman spectroscopy. This figure clearly shows that as the temperature increases, the thermal conductivity of graphene decreases.

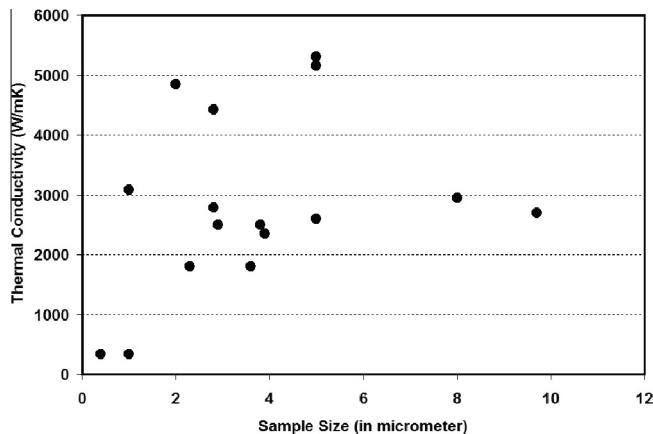
2.2. Microelectrothermal systems

Microelectrothermal systems have been used in recent years to measure the thermal conductivity of graphene [38,5,41–43,64,65]. Seol et al. [41] developed a nanofabricated resistance thermometer device to measure the thermal conductivity of graphene monolayers exfoliated onto silicon dioxide. The measurement results indicated that the thermal conductivity of the supported graphene was approximately 600 W/m K at room temperature. Dorgan et al. [42] studied the intrinsic transport properties of suspended graphene devices at high potential gradient fields and high temperatures (≥ 1000 K). Their results revealed that the thermal conductivity of graphene was 2500 W/m K at room temperature and 310 W/m K at 1000 K. Bae et al. [64] illustrated experimentally a decrease of the thermal conductivity as the width reduced to a size regime comparable to the intrinsic phonon mean free path. For instance, at room temperature, thermal conductivity \sim 230, 170, 100, and 80 W/m K was observed for graphene nanoribbons (GNRs) of width \sim 130, 85, 65, and 45 nm, respectively. Xu et al. [40] reported measurements of thermal conduction in suspended single layer graphene (SLG) grown by chemical vapor deposition

Table 1

Thermal conductivity of graphene for various conditions using Raman spectroscopy method.

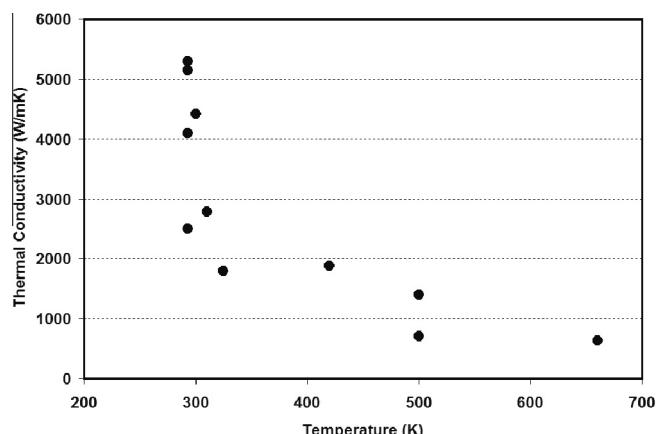
Layers	Refs.	Preparation process	Suspended/supported	Shape	Sample size μm	Laser wavelength nm	Temp. K	K (W/(m K))
<i>Experimental data</i>								
Raman spectroscopy								
SLG	[12]	Exfoliation	Suspended	Trench	2–5	488	RT	4840–5300
	[36]	Exfoliation	Suspended	Trench	1–5	488	RT	3080–5150
	[37]	Exfoliation	Suspended	Circular	2.3–3.6	514.5	325	~1800
					4.6–6.6		500	~710
	[11]	CVD	Suspended	Circular	44	632.8	660	~600
	[6]	CVD	Supported	Circular	3.8	532	350	2500+1100/–1050
					2.9		500	1400+500/–480
					3.9			~2500
	[56]	CVD	Suspended	Circular	5	532	350	~2350
					8			~2600
					9.7			~2950
					9.7			~2700
	[59]	CVD	Suspended	Circular	2.8	538	300	~3100 (air)
	[8]	CVD	Suspended	Circular	2.8	532	420	4419
	[60]	CVD	Suspended	Fine structure			RT	1875 (wrinkle free)
1								1482 (wrinkled)
2								100–1000
3	[61]	Exfoliation	Suspended	Trench			RT	4100
4								2800
8								2300
								1400
								1300
SLG								
AB-BLG	[62]	CVD	Suspended	Circular	2.8	488	310	2778 ± 569
T-BLG							314	1896 ± 410
							332	1413 ± 390
MLG	[63]	Sonication	Suspended	Trench	0.4–1 T: 20 nm	473	RT	340 (without annealing) 560 (annealing)
FLG	[57]	CVD + exfoliation	Suspended	Trench	L: 20 μm W: 13 mm	532	RT	1500–5000

**Fig. 1.** Effect of the sample size on the thermal conductivity of graphene cited in many studies using Raman Spectroscopy method based on the works in Refs. [12,36,37,56,59,62,63].

on copper (Cu-CVD). The thermal conductivity at $T = 300 \text{ K}$ in the longest sample ($L = 9 \mu\text{m}$) exhibited a value of $(1689 \pm 100) \text{ W/m K} \sim (1813 \pm 111) \text{ W/m K}$. Table 2 illustrates different values of thermal conductivity of graphene measured at various conditions. This table clearly shows significant differences between results measured using Microelectrothermal method and Raman Spectroscopy.

2.3. Scanning thermal microscopy

Scanning thermal microscopy (SThM) has been used in the literature to measure the thermal conductivity of graphene [44–47]. Yoon et al. [44] measured thermal conductivity of residue-free suspended graphene bridge using null point scanning thermal conductivity. The thermal conductivity values of graphene, whose

**Fig. 2.** Effect of the temperature on the thermal conductivity of graphene cited in many studies using Raman Spectroscopy method based on the works in Refs. [11,12,36,37,6,59,8,61,62].

length and width were 3.6 and 5.52 μm , respectively, were measured as $2430 \pm 190 \text{ W/m K}$, $2150 \pm 170 \text{ W/m K}$, and $2100 \pm 160 \text{ W/m K}$ at the peak temperatures of 335 K, 361 K, and 366 K, respectively. Yu et al. [45] investigated the temperature distributions of Joule self-heated graphene nanoribbons (GNRs) with a spatial resolution finer than 100 nm by scanning thermal microscopy. The authors estimated an upper bound of the thermal conductivity of GNR as $\sim 3800 \text{ W/m K}$. Pumarol et al. [46] reported direct imaging of nanoscale thermal transport in single and few-layer graphene (1, 3, 5, and 17 layers) with approximately 50 nm lateral resolution using high vacuum scanning thermal microscopy. The authors in a later study observed a decrease in thermal conductance of supported graphene with an increase in the number of layers. The measured results of thermal conductivity were approximately 920 W/m K, 317 W/m K, 205 W/m K, and

Table 2

Thermal conductivity of graphene for various conditions using microelectrothermal system.

Layers	Refs.	Preparation Process	Suspended/ supported	Shape	Sample size μm	Structure	Temp. K	K (W/(m K))
<i>Experimental data</i>								
Microelectrothermal system								
SLG	[38]	Exfoliation	Suspended	T	3 * 5	4-Probs	RT	2500
	[39]	Exfoliation	Suspended	T	3 * 0.5	Microresistance thermometer	280 <140	190 K-T ^{1.5}
	[40]	CVD	Suspended	T	9 * 1.5	Microresistance thermometer	RT	~1700
	[5]	Exfoliation	Supported	T	9.5–12.5 1.5–3.2	Microresistance thermometer	RT	~600
	[41]	Exfoliation	Supported	T	3 * 12.5	Microresistance thermometer	RT	~600
	[42]	Exfoliation CVD	Suspended	T	0.85 * 1.5	Microresistance thermometer	RT 1000	~2500 (anneal & vaccum)
	[43]	CVD	Suspended	T	w: 170 w: 385 w: 120 w: 40	Electro-thermal micro-bridge	300	~310 (anneal & vaccum) 240 400 1700 2200
	[64]	Exfoliation	Supported	T	w: 17 w: 0.13 w: 0.085 w: 0.065 w: 0.045	Heat spreader	RT	320 (anneal) 230 (anneal) 170 (anneal) 100 (anneal) 80 (anneal)
1	[65]	Exfoliation	encased within SiO_2	T	Sensors W: 140 & 240	Heat spreader	310	~50 (anneal)
3								~100 (anneal)
10								~300 (anneal)
20								~1000 (anneal)
BLG	[66]	Exfoliation	Suspended	T	5 * 1.8	Microresistance thermometer	RT <125	~600 (anneal) K-T ^{1.5}
BLG	[67]	Exfoliation	Suspended	T	7.5 * 5	Electro-thermal micro-bridge	RT	~900
2	[68]	Exfoliation	Suspended	T	3 * 5	T-bridge	RT	389 (without annealing) 344 (annealing) 302 (without annealing) 596 (annealing)
3								
4								
8								
2	[69]	Exfoliation	Supported	T		Electrical self-heating	300	~630 ~710 ~810 ~810 ~950
6								
8								
27								
34								
2	[70]	Exfoliation	Supported	T		Electrical self-heating	RT	640 775
8								
3	[71]	Exfoliation	Supported	T	5 * 5	Microresistance thermometer	RT	1250 (vacuum)
3			Supported	T	5 * 2	thermal-bridge		327 (vacuum)
3			Supported	T	5 * 1			150 (vacuum)
MLG			Suspended	T	5 * 1			170 (vacuum)
FLG	[66]	CVD	3D FOAM	T		Microresistance thermometer	RT	250 650 650 (annealing) 1600 (annealing) 650 (annealing) 650 (annealing)
FLG	[72]	CVD ribbons	Supported	T	0.2–1 * 0.016– 0.052	Resistance thermometer	RT	1000–1400
FLG	[73]	CVD ribbons	Supported	T	0.2–0.7 * 0.016– 0.09	Resistance thermometer	293	80
FLG	[74]	CVD-sheet Nano-ribbons	suspended	T	508 * 385	Electrical self-heating	873	130
FLG	[75]	CVD ribbons	suspended	T	0.846 * 0.169	Electro-thermal micro-bridge	198 873 80 300 380	126 (vacuum) 877 (vacuum) ~12.7 349 932
FLG	[76]	Reduced graphene oxide flakes	Supported Suspended Suspended	T	0.5 * 3	Electrical four-point	RT	2.87 0.14 0.87

65 W/m K for 1, 3, 5, and 17 layers respectively. Table 4 summarizes some of the thermal conductivity measurements of graphene using scanning thermal microscopy. Similar to the values obtained by Microelectro thermal measurements in Table 3, one can notice from this table that much smaller values of thermal conductivity of graphene are again observed here as well.

2.4. Theoretical models

The molecular dynamics simulation, which is a method for studying the physical movements of atoms and molecules, is used to determine the thermal conductivity of graphene [77–89]. For example, Nika et al. [77] suggested a simple model for the lattice

Table 3

Thermal conductivity of graphene for various conditions using scanning thermal microscopy.

Layers	Refs.	Preparation process	Suspended/ supported	Shape	Sample size (μm)	Description	Temp. (K)	K (W/(m K))
<i>Experimental data</i>								
Scanning thermal microscopy								
SLG	[44]	CVD + PDMS stamping	Suspended	T	3.6 * 5.52	Electrically heated +50 nm spatial resolution	335 361 366 RT	2430 ± 190 2150 ± 170 2100 ± 160 (vacuum + no residue) ~3800 (vacuum + no residue)
1 3 5 17	[45]	Exfoliation	Suspended	T	0.086 * 3	Joule self-heated + 100 nm spatial resolution	RT	~3800 (vacuum + no residue)
FLC flake	[46]	Exfoliation	Suspended	T	W: 0.18	Joule self-heated + 50nm spatial resolution	RT	~920 ~317 ~205 ~65 (high vacuum + no residue)
	[47]	Exfoliation	Suspended	–	–	Joule self-heated + 50nm spatial resolution	RT	~10 ~780–850 (vacuum)

thermal conductivity of graphene in the framework of Klemens approximation. They illustrated that the calculated thermal conductivity varied in the range of 1000–8000 W/m K. Munoz et al. [83] presented analytical expressions for the ballistic thermal conductance of a ribbon of limited width, approximating its phonon spectra by the vibrational modes of an elastic shell. The authors reported that the thermal conductivity was obtained for lengths exceeding the average mean free path to a value of 3960 W/m K.

Several molecular dynamic simulations in the literature have exhibited contradictory results (25 W/m K–20,000 W/m K) [85,96,99,102]. Cao [88] studied heat transport in monolayer graphene sheet using non-equilibrium molecular dynamics simulations. It was shown that the thermal transport in monolayer graphene sheet exhibited a strong length dependence on thermal conductivity; reaching 2360 W/m K at 2.8 μm . Wei et al. [91] investigated the in-plane lattice thermal conductivities of a single layer and multilayer graphene films using non-equilibrium dynamics simulations. It was found in that study the thermal conductivity of a single layer graphene was higher than that of a multilayer graphene. The results of that study showed that the in-plane thermal conductivities of a single layer, two layers, three layers, five layers, and graphite at 300 K were ~870 W/m K, ~825 W/m K, ~800 W/m K, ~575 W/m K, and ~525 W/m K, respectively. Garg et al. [93] investigated the thermal conductivity of a single layer graphene sheet by using an embedded approach of molecular dynamics (MD) and soft computing method. The effect of temperature and Stone–Thrower–Wales (STW) defects on the thermal conductivity of graphene sheet was analyzed in that study using MD simulation. The thermal conductivity of zigzag graphene sheet obtained from MD simulations was in the range of 30–80 W/m K. Table 4 shows the theoretical values of thermal conductivity of graphene for various conditions. It is interesting to note that even for theoretical models, wide discrepancies can be found in the thermal conductivity results (25 W/m K–20,000 W/m K). Figs. 3 and 4 summarize the minimum and maximum values of the thermal conductivity of graphene. It clearly seen in these figures that there is a large disagreement in the results using different methods and therefore more experimental and analytical studies should be conducted to unify these results.

3. Discussion

Thermal transport in graphene material has attracted a lot of attention as an area of research because of the potential for thermal management applications. Several measurements of the thermal conductivity of suspended graphene reported an extraordinarily large thermal conductivity compared with the thermal conductivity of diamond. Here we have presented a critical

investigation of the thermal conductivity results of graphene using different experimental techniques and theoretical models. The results of the current investigation expose major discrepancies and problems in the obtained values of the thermal conductivity of graphene reported in the literature.

Many studies were conducted in the literature and measured a wide range of thermal conductivity as depicted in Tables 1–4. Moreover, the theoretical results also display broad variations in the thermal conductivity of graphene. The large variations in the reported thermal conductivity can be caused by large measurement uncertainties as well as variations in the graphene quality and processing conditions. In addition, it is known that when a single-layer graphene is supported on an amorphous material, the thermal conductivity is reduced to about 500–600 W/m K at room temperature as a result of scattering of graphene lattice waves by the substrate [5,115,116] and can be even lower for few layer graphene encased in an amorphous oxide [65]. Similarly, polymeric residue can contribute to a similar reduction in the thermal conductivity of suspended graphene to approximately 500–600 W/m K for a bilayer graphene.

Based on the tabulated results in Tables 1–4, the high values for the graphene thermal conductivity seem to be significantly overestimated. In addition, a large variation in the thermal conductivity of graphene was noticed from the reported results using different experimental and numerical methods (0.14 W/m K–20,000 W/m K) [76,85]. Sadeghi et al. [117] reported some drawbacks of the experimental techniques for measuring thermal conductivity of graphene. For example, the major source of uncertainty in the Raman-based technique exists in the very different values of optical absorbance used in different studies. In addition to the uncertainty in the optical absorbance, the presence of local non-equilibrium may cause errors in the thermal conductivity results obtained from a data analysis based on Fourier's law [118]. Furthermore, Raman peak positions and their temperature dependence can be affected by strains and impurity amount in graphene [119,120]. These issues can result in significant errors when measuring the thermal conductivity of graphene using the Raman technique. This raises a major concern on the accuracy of the experimental techniques that were used to measure the thermal conductivity of graphene at the nanoscale level. Thus, more pertinent studies need to be conducted to accurately report the thermal conductivity of graphene under various conditions.

When materials and devices are reduced to a sufficiently small size, the thermal, electrical, and optical characteristics become clearly different from those at the macroscale and nanoscale. Microscale heat transfer becomes significant when the mean free path of the heat carrier becomes comparable to the characteristic length of the device and the continuum approach becomes invalid at this length scale. Tien and Chen [121] addressed challenges in

Table 4

Thermal conductivity of graphene using theoretical models for various conditions.

Layers	Ref.	Method	Description	K (W/(m K))
<i>Theoretical data</i>				
SLG	[77]	BTE, γ_{LA}, γ_{TA}	Strong size dependence	1000–8000
	[78]	BTE, $\gamma_s(q)$	Depends on the flake width, defect concentration and roughness of the edges	2000–5000
	[79]	BTE	$K(\text{graphene}) \geq K(\text{carbon nanotube})$	~2430
	[80]	BTE	Weak interlayer coupling	1500–3500
	[81]	BTE	Strong dimension dependence	100–8000
	[82]	Semi-continuum model	Depends on the tensile and compression strain, defects amount, and isotope concentration	2000–4000
	[83]	Ballistic elastic-shell-based theory	Strong width dependence	3960
	[84]	MD simulation	Depends on the vacancy defect concentrations	2903 ± 93
	[85]	Valence force field model (VFFM)	Ballistic region	20,000
	[86]	Non-equilibrium MD simulation	Strong length and defect density dependence	100 to ~550
	[87]	MD simulation	Length ~16 μm, strong length dependence	3200
	[88]	MD simulation	Strong length dependence	2360
	[89]	MD simulation	Strong strain dependence	~3500 to ~5500
	[90]	MD simulation and relaxation time approximation (RTA) method	Isolated size $60 \times 60 \text{ \AA}$	1779.7
	[90]	MD simulation and relaxation time approximation (RTA) method	60x60 Å sheet; Cu-supported; dependents on the interaction strength between graphene and substrate	1281.5
	[91]	MD simulation	Length (7–25 nm), strong bonding strength dependence	~870
	[92]	MD simulation	Strong defect concentration dependence	1720 (No defects) ~100–180 (with defects)
	[93]	MD simulation	Strong defect concentration dependence	30–80
	[94]	MD + finite element modeling	Strong dependence on the grain boundary contact resistance and grain size	–
	[95]	BTE	$L \sim 10 \mu\text{m}$; Strong dependence on the direction of acoustic, isotopic percentages, temperature and L ; insensitive to strain.	800–3500
	[50]	BTE	Strong dependence on the isotopic percentages, temperature and L	500–5000
	[40]	MD simulation	$L: 300 \text{ nm} \sim 9 \mu\text{m}$; dependence on the temperature and sample length	50–2300
	[96]	MD simulation	$L: 20.5 \text{ nm}$ Dependence on the geometric variation of doped boron and temperature	~25–80
	[48]	MD simulation	$k(r_G) = k_{c-\text{Graph}}/(1 + R_{GB} * k_{c-\text{Graph}}/2r_G)$; $k(c_{GB}) = k_{c-\text{Graph}}/(1 + c_{GB} * R_{GB} * k_{c-\text{Graph}}/d_i)$	~24–860
	[97]	BTE + MD	Temperature-dependent; length-dependent; width-dependent	<1000
	[98]	MD simulation	Strong dependence on carbonyl pairs and vacancies lead; Weak dependence on hydroxyl, epoxy groups and nano-holes	~60–3500
	[99]	BTE	$L: 3, 10, 100 \mu\text{m}$; Dependence on Length, temperature, LA, TA and ZA	~600–8000
	[49]	First principles BPE	Size-dependent and stain-dependent when sample larger than 500 μm; temperature-dependent	<20,000
FLG	[61]	BTE, $\gamma_s(q)$	$n = 8 - 1$, strong size dependence	1000–4000
	[80]	BTE	$n = 5 - 1$, strong size dependence	1000–3500
	[100]	Linearized Boltzmann transport equation and perturbation theory	$n = 4 - 1$	2000–3300
	[91]	MD simulation	$n = 5 - 1$, strong dependence on the bonding strength	580–880
	[101]	Semi-continuum model	$n = 10 - 1$, strong dependence on the number of layers, temperature and L_c	~2700–5000
GNRs 7000 ~ 20,000	[102]	MD simulation	Strong function of the ribbon width Graphene sheet size: ~20 A	~500–
	[103]	BTE + Full phonon dispersions	Depend strongly on the width of the nanoribbon and the rms height of the edge roughness	~5500
	[4]	MD simulation	At 400 K for a 1.5 nm × 5.7 nm zigzag GNR), Depends on vacancies and edge roughness in ~2000 the nanoribbons	~2000
	[104,105]	AIREBO potential + MD simulation	Strong defect density dependence	30–80
	[106]	MD simulation	Extremely sensitive to defect configuration; strong length dependence	3000–5200
	[107]	MD simulation	$K \sim L^{0.24}$, $100 \text{ nm} \leq L \leq 650 \text{ nm}$	400–600
	[108]	MD simulation	$10 \text{ nm}^2 \cdot 2.1 \text{ nm}$; Strong tensile strain dependence; insensitive to compressive strain	~75
	[109]	MD simulation	$2 \text{ nm}^2 \cdot 11 \text{ nm}$; dependence on N shape doping, N atom doping concentration	20–95
	[51]	MD simulation	Dependence on the edge effects	70–100
	[52]	MD simulation	$50 \text{ nm}^2 \cdot 4.26 \text{ nm}$; Strong dependence on the isotopic percentages	–
	[53]	MD simulation	$20–110 \text{ nm}^2 \cdot 4.26 \text{ nm}$; dependence on the length and isotopic	~86–215
	[54]	Direction-dependent phonon-boundary scattering + BTE	$L: 10 \mu\text{m}; W: 0.5, 1, 0.5, 0.5 \mu\text{m}$; Dependence on the effects of size and temperature , LA, TA ~250–7000 and ZA branches	~250–7000
	[55]	MD simulation	ZGNRs have better torsional rigidity than AGNRs; The thermal conductivity of length-fixing GNRs decreases with the increase of torsional deformation and temperature; The wider GNRs have better anti-torsion capability and thermal conductivity	~50–500
	[110]	BTE	$W < 1.5 \mu\text{m}$, weak width-dependent; MFPs > 1 μm, strong long MFP phonons-dependent	~2000
	[111]	BTE	Dependence on length, width, temperature and roughness	<6000
GNRs on SiO ₂	[112]	BTE	Strong edge and width dependence	100–1000
FIGNRs	[113]	MD simulation	10-ZGNR, $n = 1, \dots, 5$	300–500
FLGNRs on SiO ₂	[114]	MD simulation	Dependence on the equivalent molecule number density(ρ) and Number of molecules(N)	520–700

the field of micro-length scale radiative and conductive heat transfer in solids. A number of experimental works have reported a reduced thermal conductivity at the microscale [120,122]. Yu

et al. [122] investigated the temperature dependence of aluminum gallium arsenide (GaAs/AlAs) thin film structures. Their results demonstrated that the thermal conductivity/diffusivity of the

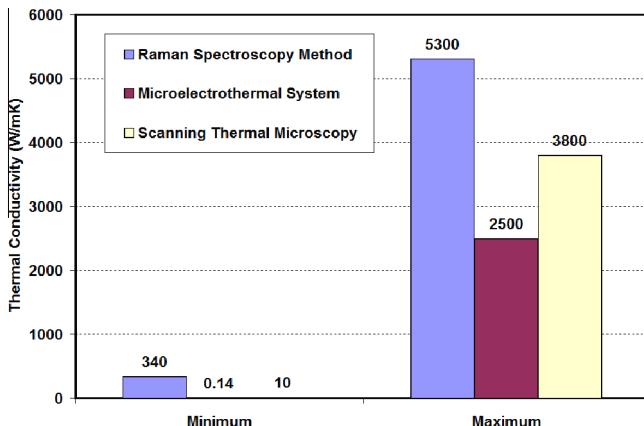


Fig. 3. Variation of thermal conductivity of graphene using different experimental methods based on the works in Refs. [12,63,76,42,45,47].

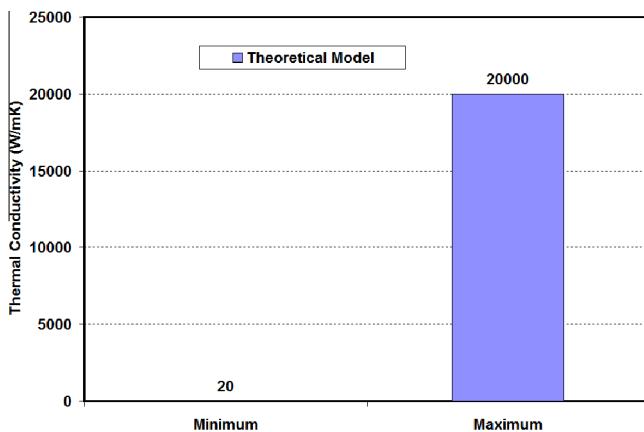


Fig. 4. Variation of thermal conductivity of graphene using theoretical model based on the works in Refs. [85,102,109].

structure were lower than its corresponding bulk values. The temperature dependence of its thermophysical properties was weaker than that of the typical bulk materials. Interface scattering was believed to be the major cause of the observed reduction in the thermal conductivity.

Chen et al. [120] developed a measurement technique that determined the thermal diffusivity of thin films in both parallel and perpendicular directions, and presented experimental results on the thermal diffusivity of GaAs/AlGaAs-based thin-film structures. The results demonstrated that the thermal diffusivity of the vertical-cavity surface-emitting laser (VCSEL) structure was 5–7 times smaller than that of its corresponding bulk media. The authors attributed this large difference to the anisotropy of thermal diffusivity caused solely by the effects of interfaces and boundaries of the thin film. Contrary to the prior analyzed results, the above examples actually show deterioration in the thermal properties as compared to bulk properties. Piprek [123] presented direct thermal conductivity measurements of separated GaAs-AlAs DBRs (distributed Bragg reflectors) with a quarter-wave layer thickness of more than 100 nm. Using an ac calorimetric method and finite element analysis, a 50% thermal conductivity reduction was found compared to the average bulk value.

It should be noted that the thermal conductivity is a macro manifestation of a measure that shows a substance's ability to transfer the heat. As such the measurement of the ability of a single layer of carbon atoms to carry the heat itself comes into question. The huge disparities in the obtained values for the thermal conduction

of Graphene further aggravates the problem. Understanding energy transport mechanisms at the micro- and nano-scale becomes increasingly important. This requires accurate investigation of material properties, along with the development of new technologies to characterize energy transfer at these scales.

4. Conclusions

A comprehensive synthesis of the thermal conductivity of a single layer graphene (SLG), few layer graphene (FLG), multiple-layer graphene (MLG), and nanoribbons graphene (NRG) was presented in this work. The results of different experimental and theoretical techniques were summarized in Tables 1–4 for various conditions such as preparation process, shape, sample size, wavelength, and temperature. Wide variations in the thermal conductivity results were reported in different studies. The initially measured thermal conductivity appears to be considerably overestimated. Majority of the cited studies subsequently reported lower values of thermal conductivity than the earlier published results. Moreover, significant inconsistency in the results were noticed in the results of the thermal conductivity of graphene using various experimental and theoretical techniques (0.14 W/m K–20,000 W/m K). Most of the experimental methods unanimously illustrated the dependence of graphene thermal conductivity results on temperature. Raman spectroscopy illustrated that the thermal conductivity of graphene decreases with an increase in the temperature. Disagreement was also reported on the effect of sample size on the thermal conductivity results of graphene. The initially reported results showed sample size dependence while the subsequent studies illustrated insignificant effect of the sample size. Thus, more experimental and theoretical studies should be conducted to accurately determine the thermal conductivity of graphene.

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